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CONFIRMATION NO. 4607

Bib Data Sheet

SERIAL NUMBER 10/512,405	FILING OR 371(c) DATE 06/15/2005 RULE	CLASS 438	GROUP ART UNIT 2812	ATTORNEY DOCKET NO. 474082002800
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APPLICANTS

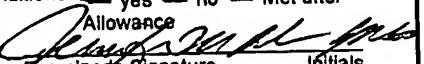
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** CONTINUING DATA *****

This application is a 371 of PCT/JP03/04866 04/16/2003

** FOREIGN APPLICATIONS *****

JAPAN 2002-127509 04/26/2002
 JAPAN 2002-360731 12/12/2002

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and Acknowledged  Examiner's Signature Initials	STATE OR COUNTRY JAPAN	SHEETS DRAWING 6	TOTAL CLAIMS 17	INDEPENDENT CLAIMS 4
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ADDRESS

25227

TITLE

High resistance silicon wafer and method for production thereof

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